

# Johannes Binder

## List of Publications by Year in descending order

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28  
papers

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citations

933447  
10  
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docs citations

28  
times ranked

1058  
citing authors

#	ARTICLE	IF	CITATIONS
1	Strain control in graphene on GaN nanowires: Towards pseudomagnetic field engineering. <i>Carbon</i> , 2022, 186, 128-140.	10.3	1
2	Raman Optical Activity of 1T-TaS <sub>2</sub> . <i>Nano Letters</i> , 2022, 22, 2835-2842.	9.1	10
3	Charge Transfer in 1T-TaS <sub>2</sub> /Graphene Hybrid Structures Studied by Spatially Resolved Raman Spectroscopy. <i>Acta Physica Polonica A</i> , 2021, 139, 311-313.	0.5	0
4	Delamination of Large Area Layers of Hexagonal Boron Nitride Grown by MOVPE. <i>Acta Physica Polonica A</i> , 2021, 139, 457-461.	0.5	4
5	Suspended graphene on germanium: selective local etching via laser-induced photocorrosion of germanium. <i>2D Materials</i> , 2021, 8, 035043.	4.4	3
6	Towards practical applications of quantum emitters in boron nitride. <i>Scientific Reports</i> , 2021, 11, 15506.	3.3	6
7	Highly effective gating of graphene on GaN. <i>Applied Surface Science</i> , 2021, 560, 149939.	6.1	3
8	Two stage epitaxial growth of wafer-size multilayer h-BN by metal-organic vapor phase epitaxy – a homoepitaxial approach. <i>2D Materials</i> , 2021, 8, 015017.	4.4	20
9	Heteroepitaxial Growth of High Optical Quality, Wafer-Scale van der Waals Heterostructures. <i>ACS Applied Materials &amp; Interfaces</i> , 2021, 13, 47904-47911.	8.0	14
10	Impeded phase transition in 1T-TaS <sub>2</sub> : Thermoelectric fingerprint of long-lived mixed states. <i>Solid State Communications</i> , 2020, 305, 113749.	1.9	9
11	Spatially resolved thermoelectric response of mixed states. , 2020, , .		0
12	Upconverted electroluminescence via Auger scattering of interlayer excitons in van der Waals heterostructures. <i>Nature Communications</i> , 2019, 10, 2335.	12.8	51
13	An Influence of X-Ray Irradiation on Mid-Bandgap Luminescence of Boron Nitride Epitaxial Layers. <i>Acta Physica Polonica A</i> , 2019, 136, 620-623.	0.5	0
14	Electronic structure of commensurate, nearly commensurate, and incommensurate phases of $\sqrt{m}\times\sqrt{m}$ superlattices. <i>Physical Review B</i> , 2018, 98, . Sub-bandgap Voltage Electroluminescence and Magneto-oscillations in a WSe <sub>2</sub> Light-Emitting van der Waals Heterostructure. <i>Nano Letters</i> , 2017, 17, 1425-1430.	3.2	29
15	The optical response of monolayer, few-layer and bulk tungsten disulfide. <i>Nanoscale</i> , 2017, 9, 13128-13141.	5.6	97
16	In Situ Raman Spectroscopy of Solution-Gated Graphene on Copper. <i>Acta Physica Polonica A</i> , 2017, 132, 360-363.	0.5	1
17	Multiple magneto-phonon resonances in graphene. <i>2D Materials</i> , 2016, 3, 015004.	4.4	8

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19	<i>In situ</i> Raman spectroscopy of the graphene/water interface of a solution-gated field-effect transistor: electron-phonon coupling and spectroelectrochemistry. <i>Nanotechnology</i> , 2016, 27, 045704.	2.6	9
20	The disorder-induced Raman scattering in Au/MoS <sub>2</sub> heterostructures. <i>AIP Advances</i> , 2015, 5, .	1.3	27
21	A micro-magneto-Raman scattering study of graphene on a bulk graphite substrate. <i>Europhysics Letters</i> , 2014, 108, 27011.	2.0	6
22	Graphene Based Flow Sensors. <i>Acta Physica Polonica A</i> , 2014, 126, 1209-1212.	0.5	1
23	Nitrogen doping of chemical vapor deposition grown graphene on 4H-SiC (0001). <i>Journal of Applied Physics</i> , 2014, 115, .	2.5	27
24	Modification of Emission Properties of ZnO Layers due to Plasmonic Near-Field Coupling to Ag Nanoislands. <i>Plasmonics</i> , 2013, 8, 913-919.	3.4	7
25	Dynamics of thermalization in GaInN/GaN quantum wells grown on ammonothermal GaN. <i>Journal of Applied Physics</i> , 2013, 114, .	2.5	14
26	Optical Properties of Molybdenum Disulfide (MoS <sub>2</sub> ). <i>Acta Physica Polonica A</i> , 2013, 124, 849-851.	0.5	42
27	Photoluminescence Dynamics of GaN/Si Nanowires. <i>Acta Physica Polonica A</i> , 2012, 122, 1001-1003.	0.5	7
28	Absorption and Emission Properties of Light Emitting Diode Structures Containing GaInN/GaN QWs. <i>Acta Physica Polonica A</i> , 2011, 120, 918-920.	0.5	1